

2.0x1.25mm SMD CHIP LED LAMP

Part Number: KP-2012SRC-J4 Super Bright Red

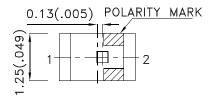
Features

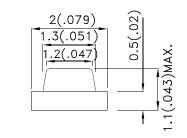
- 2.0mmx1.25mm SMT LED,1.1mm thickness.
- Low power consumption.
- Wide viewing angle.
- Ideal for backlight and indicator.
- Various colors and lens types available.
- Package: 2000pcs / reel.
- Moisture sensitivity level : level 3.
- RoHS compliant.

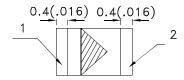
Description

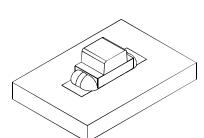
The Super Bright Red source color devices are made with AlGaInP on Si substrate Light Emitting Diode.

Package Dimensions













Notes:

- All dimensions are in millimeters (inches).
 Tolerance is ±0.1(0.004") unless otherwise noted.
- 3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

 4. The device has a single mounting surface. The device must be mounted according to the specifications.

SPEC NO: DSAM7801 **REV NO: V.1A** DATE: DEC/04/2012 PAGE: 1 OF 5 APPROVED: WYNEC **CHECKED: Allen Liu** DRAWN: F.Cui ERP: 1203013571

Selection Guide

Part No.	Dice	Lens Type	lv (mcd) [2] @ 20mA		Viewing Angle [1]
		,	Min.	Тур.	201/2
KP-2012SRC-J4	Super Bright Red (AlGaInP)	Water Clear	400	600	120°
KF-20125KC-J4		Water Clear	*120	*200	

- 1. θ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Red	660		nm	IF=20mA
λD [1]	Dominant Wavelength	Super Bright Red	640		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Red	20		nm	IF=20mA
С	Capacitance	Super Bright Red	45		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Super Bright Red	2.1	2.5	V	IF=20mA
lr	Reverse Current	Super Bright Red		10	uA	V _R =5V

- 1.Wavelength: +/-1nm.
- 2. Forward Voltage: +/-0.1V.
 3. Wavelength value is traceable to the CIE127-2007 compliant national standards.

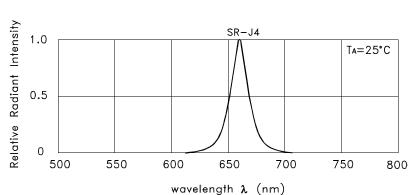
Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Red	Units	
Power dissipation	75	mW	
DC Forward Current	30	mA	
Peak Forward Current [1]	150	mA	
Reverse Voltage	5	V	
Operating Temperature	-40°C To +85°C		
Storage Temperature	-40°C To +85°C		

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

SPEC NO: DSAM7801 **REV NO: V.1A** DATE: DEC/04/2012 PAGE: 2 OF 5 APPROVED: WYNEC **CHECKED: Allen Liu** DRAWN: F.Cui ERP: 1203013571

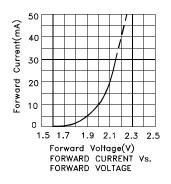
Luminous intensity/ luminous Flux: +/-15%.
 *Luminous intensity value is traceable to the CIE127-2007 compliant national standards.

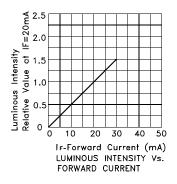


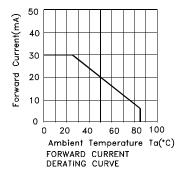
RELATIVE INTENSITY Vs. WAVELENGTH

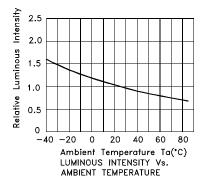
Super Bright Red

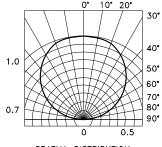
KP-2012SRC-J4











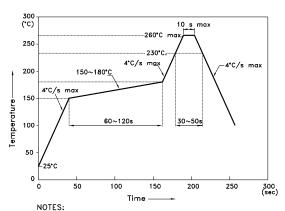
SPATIAL DISTRIBUTION

SPEC NO: DSAM7801 REV NO: V.1A DATE: DEC/04/2012 PAGE: 3 OF 5
APPROVED: WYNEC CHECKED: Allen Liu DRAWN: F.Cui ERP: 1203013571

KP-2012SRC-J4

Reflow soldering is recommended and the soldering profile is shown below. Other soldering methods are not recommended as they might cause damage to the product.

Reflow Soldering Profile For Lead-free SMT Process.



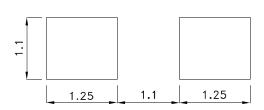
- NOTES:

 1.We recommend the reflow temperature 245°C(+/-5°C). The maximum soldering temperature should be limited to 260°C.

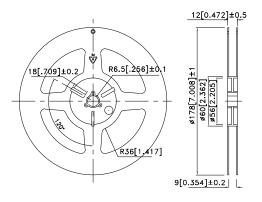
 2.Don't cause stress to the epoxy resin while it is exposed to high temperature.

 3.Number of reflow process shall be 2 times or less.

Recommended Soldering Pattern (Units: mm; Tolerance: ± 0.1)



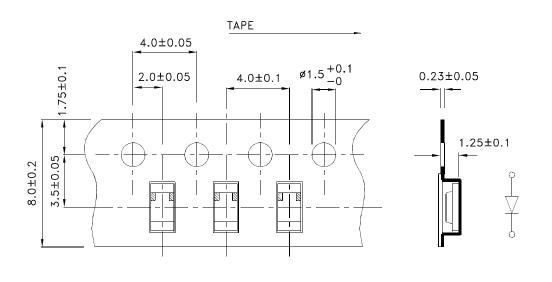
Reel Dimension



PAGE: 4 OF 5

ERP: 1203013571

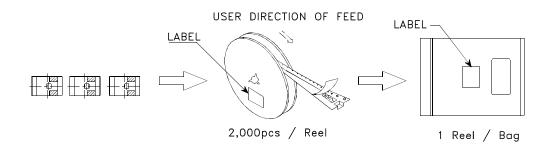
Tape Dimensions (Units: mm)

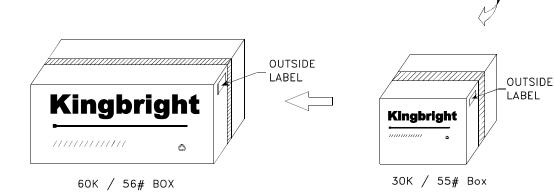


SPEC NO: DSAM7801 **REV NO: V.1A DATE: DEC/04/2012** APPROVED: WYNEC **CHECKED: Allen Liu** DRAWN: F.Cui

PACKING & LABEL SPECIFICATIONS

KP-2012SRC-J4







Detailed application notes are listed on our website. http://www.kingbright.com/application_notes

SPEC NO: DSAM7801 APPROVED: WYNEC REV NO: V.1A CHECKED: Allen Liu DATE: DEC/04/2012 DRAWN: F.Cui PAGE: 5 OF 5 ERP: 1203013571